

Dual 4-Input NAND Gate

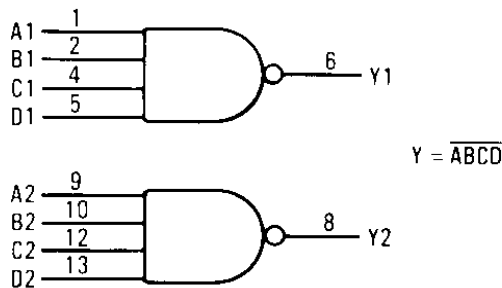
High-Performance Silicon-Gate CMOS

The SL74HCT20 is identical in pinout to the LS/ALS20. The SL74HCT20 may be used as a level converter for interfacing TTL or NMOS outputs to High-Speed CMOS inputs.

- TTL/NMOS-Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 μ A
- High Noise Immunity Characteristic of CMOS Devices

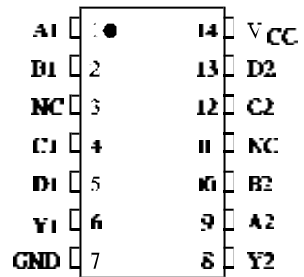


LOGIC DIAGRAM



PIN 14 = V_{CC}
 PIN 7 = GND
 PINS 3,11 = NO CONNECTION

PIN ASSIGNMENT



NC = NO CONNECTION

FUNCTION TABLE

| Inputs | | | | Output |
|--------|---|---|---|--------|
| A | B | C | D | Y |
| L | X | X | X | H |
| X | L | X | X | H |
| X | X | L | X | H |
| X | X | X | L | H |
| H | H | H | H | L |

X = don't care

SL74HCT20

MAXIMUM RATINGS*

| Symbol | Parameter | Value | Unit |
|------------------|--|------------------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | -0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage (Referenced to GND) | -1.5 to V _{CC} +1.5 | V |
| V _{OUT} | DC Output Voltage (Referenced to GND) | -0.5 to V _{CC} +0.5 | V |
| I _{IN} | DC Input Current, per Pin | ±20 | mA |
| I _{OUT} | DC Output Current, per Pin | ±25 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GND Pins | ±50 | mA |
| P _D | Power Dissipation in Still Air, Plastic DIP+ SOIC Package+ | 750 500 | mW |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package) | 260 | °C |

*Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.
+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package: - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|------------------------------------|--|-----|-----------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | 4.5 | 5.5 | V |
| V _{IN} , V _{OUT} | DC Input Voltage, Output Voltage (Referenced to GND) | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time (Figure 1) | 0 | 500 | ns |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| Symbol | Parameter | Test Conditions | V _{CC} V | Guaranteed Limit | | | Unit |
|------------------|--|---|----------------------|----------------------|----------------|------------|------|
| | | | | 25 °C to -55°C | ≤85 °C | ≤125 °C | |
| V _{IH} | Minimum High-Level Input Voltage | V _{OUT} =0.1 V or V _{CC} -0.1 V I _{OUT} ≤ 20 μA | 4.5 | 2.0 | 2.0 | 2.0 | V |
| | | | 5.5 | 2.0 | 2.0 | 2.0 | |
| V _{IL} | Maximum Low-Level Input Voltage | V _{OUT} =0.1 V or V _{CC} -0.1 V I _{OUT} ≤ 20 μA | 4.5 | 0.8 | 0.8 | 0.8 | V |
| | | | 5.5 | 0.8 | 0.8 | 0.8 | |
| V _{OH} | Minimum High-Level Output Voltage | V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA | 4.5 | 4.4 | 4.4 | 4.4 | V |
| | | 5.5 | 5.4 | 5.4 | 5.4 | | |
| V _{OL} | Maximum Low-Level Output Voltage | V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 4.0 mA | 4.5 | 3.98 | 3.84 | 3.7 | V |
| | | 5.5 | 0.1 | 0.1 | 0.1 | | |
| V _{OL} | Maximum Low-Level Output Voltage | V _{IN} =V _{IH} I _{OUT} ≤ 20 μA | 4.5 | 0.1 | 0.1 | 0.1 | V |
| | | 5.5 | 0.1 | 0.1 | 0.1 | | |
| I _{IN} | Maximum Input Leakage Current | V _{IN} =V _{CC} or GND | 4.5 | 0.26 | 0.33 | 0.4 | μA |
| | | | 5.5 | ±0.1 | ±1.0 | ±1.0 | |
| I _{CC} | Maximum Quiescent Supply Current (per Package) | V _{IN} =V _{CC} or GND I _{OUT} =0μA | 5.5 | 2.0 | 20 | 40 | μA |
| ΔI _{CC} | Quiescent Additional Supply Current | V _{IN} =2.4 V, Any One Input V _{IN} =V _{CC} or GND, Other Inputs I _{OUT} =0μA | 5.5 | ≥-55 °C | 25 °C to 125°C | | mA |
| | | | | 2.9 | 2.4 | | |

SL74HCT20

AC ELECTRICAL CHARACTERISTICS ($V_{CC}=5.0\text{ V} \pm 10\%$, $C_L=50\text{ pF}$, Input $t_r=t_f=6.0\text{ ns}$)

| Symbol | Parameter | Guaranteed Limit | | | Unit |
|--------------------|--|------------------|-------|--------|------|
| | | 25 °C to -55°C | ≤85°C | ≤125°C | |
| t_{PLH}, t_{PHL} | Maximum Propagation Delay, Input A ,B,C or D to Output Y (Figures 1 and 2) | 28 | 35 | 42 | ns |
| t_{TLH}, t_{THL} | Maximum Output Transition Time, Any Output (Figures 1 and 2) | 15 | 19 | 22 | ns |
| C_{IN} | Maximum Input Capacitance | 10 | 10 | 10 | pF |

| | | | | |
|----------|--|--------------------------------------|--|----|
| C_{PD} | Power Dissipation Capacitance (Per Gate) | Typical @25°C, $V_{CC}=5.0\text{ V}$ | | pF |
| | Used to determine the no-load dynamic power consumption: $P_D=C_{PD}V_{CC}^2f+I_{CC}V_{CC}$ | 29 | | |

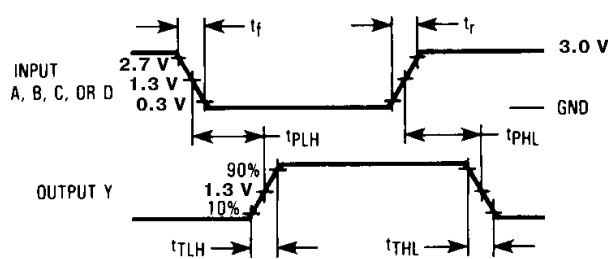
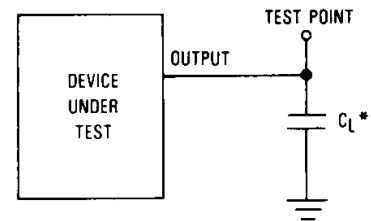


Figure 1. Switching Waveforms



*Includes all probe and jig capacitance.

Figure 2. Test Circuit

EXPANDED LOGIC DIAGRAM (1/2 of the Device)

